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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/676,963		10/01/2003	Remigijus Gaska	SETI-0004	8123	
23550	7590	11/17/2004		EXAMINER:		
		VARNICK & D'ALESSANDRO, LLC		FORDE, REMMON R		
3 E-COMM ALBANY,				ART UNIT PAPER NUMBER		
ŕ				2826		
				DATE MAILED: 11/17/2004	4	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)		
•	10/676,963	GASKA ET AL.		
Office Action Summary	Examiner	Art Unit		
	Remmon R. Fordé	2826	Bul	
The MAILING DATE of this communicat			ress	
Period for Reply				
A SHORTENED STATUTORY PERIOD FOR THE MAILING DATE OF THIS COMMUNICA - Extensions of time may be available under the provisions of 37 after SIX (6) MONTHS from the mailing date of this communic - If the period for reply specified above is less than thirty (30) da - If NO period for reply is specified above, the maximum statutor - Failure to reply within the set or extended period for reply will, Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	TION. 'CFR 1.136(a). In no event, however, may a reation. ys, a reply within the statutory minimum of thirt ry period will apply and will expire SIX (6) MON by statute, cause the application to become AB	eply be timely filed y (30) days will be considered timely. THS from the mailing date of this com ANDONED (35 U.S.C. § 133).	nmunication.	
Status				
1) Responsive to communication(s) filed o	n <u>18 August 2004</u> .			
2a)⊠ This action is FINAL . 2b)[☐ This action is non-final.			
3) Since this application is in condition for	allowance except for formal matt	ers, prosecution as to the r	merits is	
closed in accordance with the practice t	under <i>Ex part</i> e Q <i>uayl</i> e, 1935 C.D	. 11, 453 O.G. 213.		
Disposition of Claims				
4)⊠ Claim(s) <u>1-20</u> is/are pending in the appl	ication.			
4a) Of the above claim(s) is/are v	vithdrawn from consideration.			
5)⊠ Claim(s) <u>12-20</u> is/are allowed.				
6)⊠ Claim(s) <u>1-11</u> is/are rejected.				
7) Claim(s) is/are objected to.				
8) Claim(s) are subject to restriction	n and/or election requirement.			
Application Papers				
9) The specification is objected to by the E	xaminer.			
10) The drawing(s) filed on is/are: a)		by the Examiner.		
Applicant may not request that any objection	n to the drawing(s) be held in abeyan	ce. See 37 CFR 1.85(a).		
Replacement drawing sheet(s) including the	correction is required if the drawing(s) is objected to. See 37 CFF	R 1.121(d).	
11)☐ The oath or declaration is objected to by	the Examiner. Note the attached	Office Action or form PTC) - 152.	
Priority under 35 U.S.C. § 119			•	
12)☐ Acknowledgment is made of a claim for	foreign priority under 35 U.S.C. &	119(a)-(d) or (f)		
a) All b) Some * c) None of:	toroign phonty andor oo o.o.o. 3	110(a) (a) or (i).		
1. Certified copies of the priority doc	cuments have been received.			
2. Certified copies of the priority doc		pplication No		
3. Copies of the certified copies of the	he priority documents have been	received in this National S	tage	
application from the International	Bureau (PCT Rule 17.2(a)).			
* See the attached detailed Office action for	or a list of the certified copies not	received.		
Attachmont/c)				
Attachment(s) 1) X Notice of References Cited (PTO-892)	4) Interview S	ummary (PTO-413)		
2) 🔲 Notice of Draftsperson's Patent Drawing Review (PTO-	948) Paper No(s	s)/Mail Date	450	
 Information Disclosure Statement(s) (PTO-1449 or PTC Paper No(s)/Mail Date 	0/SB/08) 5)	formal Patent Application (PTO-1	152)	
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DETAILED ACTION

Response to Arguments

Applicant's arguments with respect to claims 1-11 have been considered but are moot in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ito et al. in view of Byun et al..

Regarding claims 1, 3-5, 8-11, referencing Figure 8, Ito et al. discloses a semiconductor structure provided with a substrate (11); a first layer (31) formed above the substrate; and a textured nitride layer (35) formed on the first layer. (Abstract)

Regarding claim 2, referencing Figure 8, Ito et al. further discloses providing a metal layer (20) formed above the textured nitride layer. (Abstract)

Regarding claim 6, referencing Figure 8, Ito et al. further discloses that the semiconductor structure is used in a light-emitting device (30). (Abstract)

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Regarding claim 7, referencing Figure 8, Ito et al. further discloses that the first layer (31) comprises a crystalline nitride layer (i.e. AIN). (Abstract)

Unfortunately, regarding claim 1, Ito et al. fails to disclose providing a buffer layer between the substrate and the first layer.

However, referencing Figures 6A-6B, Byun et al. discloses providing a buffer layer (31) between a substrate layer (30) and a textured nitride layer (32). (Column 5, lines 27-61.)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to provide a buffer layer as disclosed by Byun in the semiconductor device as disclosed by Ito et al. in order to protect the substrate from the overlying textured nitride layer. (Column 5, lines 27-61.)

Allowable Subject Matter

Claims 12-20 are allowed.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Contact Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Remmon R. Fordé whose telephone number is (571) 272-1916. The examiner can normally be reached on Monday-Thursday (8:00-6:30).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J. Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Remmon R. Fordé

NATHAN J. FLYNN SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800